NSN 5961-01-171-1969

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Inclosure Material:

Plastic and metal

Overall Length:

0.705 inches

Terminal Length:

0.381 inches

Overall Height:

0.546 inches

Overall Width:

0.400 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact-darlington connected

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220ab

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 collector to emitter voltage/static/base open and 80.0 collector to emitter voltage, dc with base short-circuited to emitter and 7.0

emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 1.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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